

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L14	1	("6337259").PN.	USPAT	OR	OFF	2005/03/20 17:54
L15	1	("6162667").PN.	USPAT	OR	OFF	2005/03/20 18:17
L16	1	("6670259").PN.	USPAT	OR	OFF	2005/03/20 18:14
L17	1	("6376336").PN.	USPAT	OR	OFF	2005/03/20 18:17
L18	37	("3936858" "4498227" "5194395" "5244819" "5272104" "5443661" "5453153" "5501993" "5646053" "5753560" "5773152" "5786231" "5795809" "5807771" "5818085" "5882990" "5899732" "5926727" "5929508" "5965917" "5976956" "6001711" "6010950" "6013584" "6022793" "6024888" "6083324" "6093624" "6100202" "6114223" "6133123" "6255195" "6284629" "6444534" "6534380" "6548382" "6569749").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/03/20 18:18
L19	2524	(crystall\$7 or (re adj crystall\$7)) same irradiat\$3 same (ion\$1 or (ion adj implant\$5) or dop\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 19:04
L20	684	((crystall\$7 or (re adj crystall\$7)) near5 irradiat\$3) same (ion\$1 or (ion adj implant\$5) or dop\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:56
L21	550	20 and laser\$1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:56
L22	0	21 and ((re adj distribut\$4) near5 (ion\$1 or (ion adj implant\$5) or dop\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:58

L23	81	((re adj distribut\$4) near5 (ion\$1 or (ion adj implant\$5) or dop\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:58
L24	0	23 and 20	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:59
L25	0	23 and 19	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:59
L26	16	23 and (crystall\$7 or (re adj crystall\$7))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 19:01
L27	0	26 not 23	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 19:01
L28	65	23 not 26	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 19:01
L29	6121	(ion\$1 or (ion adj implant\$5) or dop\$3) near (semiconductor near (layer or film))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 19:07
L30	1	29 and 23	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 19:06

L31	165016	(irradiat\$3 near laser or (laser adj light))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 19:07
L32	28366	31 same semiconductor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 19:07
L33	2531	32 same (crystall\$7 or (re adj crystall\$7))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 19:08
L34	367	33 same (ion\$1 or (ion adj implant\$5) or dop\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 19:16
L35	1	("6562067").PN.	USPAT	OR	OFF	2005/03/20 19:16
L36	1	("6682964").PN.	USPAT	OR	OFF	2005/03/20 19:16
S1	17	((("6165876") or ("4199773") or ("4463492") or ("4775641") or ("5403762") or ("5064775") or ("4168990") or ("5532175") or ("5565690") or ("4169740") or ("5501989") or ("5244820") or ("20020006705") or ("20020014625") or ("20020048864") or ("20020098628") or ("20020004292")).PN.	US-PGPUB; USPAT	OR	OFF	2005/03/17 14:26
S2	10131	((438/149) or (438/150) or (438/151) or (438/163) or (438/166) or (438/197) or (438/198) or (438/217) or (438/289) or (438/479) or (438/482) or (438/486) or (438/488) or (438/495) or (438/499) or (438/501) or (438/505) or (438/508) or (438/514) or (438/517) or (438/914)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/17 14:38

S3	351	S2 and (igfet or (insulated adj gate adj field adj effect adj transistor\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/17 15:06
S4	155	S3 and (((ion near2 implant\$5) or dop\$3) near5 (((single or mono) near2 crystall\$4) or semiconductor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/17 18:34
S5	109	S4 and (surface near3 (((single or mono) near2 crystall\$4) or semiconductor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/17 15:07
S6	23	("4266986" "4322253" "4375993" "4514895" "4619034" "4719183" "4727044" "4743567" "4768076" "4769338" "4775641" "4799097" "4885258" "4888305" "4916504" "4918510" "5162239" "5236850" "5264383" "5278093" "5313076" "5365080" "5619044").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/03/17 14:52
S7	10629	(igfet or (insulated adj gate adj field adj effect adj transistor\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/17 15:06
S8	1740	S7 and (((ion near2 implant\$5) or dop\$3) near5 (((single or mono) near2 crystall\$4) or semiconductor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/17 15:06
S9	1079	S8 and (surface near3 (((single or mono) near2 crystall\$4) or semiconductor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/17 15:08

S10	889	S9 and (remov\$3 or etch\$3 near4 (surface near3 (((single or mono) near2 crystall\$4) or semiconductor)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/17 15:08
S11	334	S10 and ((impurit\$3 or conductiv\$3 or boron) near5 (surface near3 (((single or mono) near2 crystall\$4) or semiconductor)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/17 18:37
S12	308	S11 not S5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/17 15:12
S13	237	S12 and (channel near2 (region or portion))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/17 16:07
S14	1	("6436745").PN.	USPAT	OR	OFF	2005/03/17 16:07
S15	2	("6133119" "6197626").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/03/17 16:07
S16	5	("6436745").URPN.	USPAT	OR	OFF	2005/03/17 16:18
S17	4	"6376336"	USPAT	OR	OFF	2005/03/17 16:18
S18	1	("6376336").PN.	USPAT	OR	OFF	2005/03/17 16:18
S19	30	("3936858" "4498227" "5194395" "5244819" "5272104" "5443661" "5453153" "5501993" "5646053" "5753560" "5773152" "5795809" "5807771" "5818085" "5882990" "5899732" "5926727" "5929508" "5965917" "5976956" "6001711" "6010950" "6013584" "6022793" "6024888" "6083324" "6093624" "6100202" "6114223" "6133123").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/03/17 16:19

S20	8901	((ion near2 implant\$5) or dop\$3) near5 (surface near4 (((single or mono) near2 crystall\$4) or semiconductor)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/17 18:35
S21	725	((ion near2 implant\$5) or dop\$3) near (surface near (((single or mono) near2 crystall\$4) or semiconductor)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/17 18:52
S22	569	S21 and (impurit\$3 or conductiv\$3 or boron)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/17 18:39
S23	102	S22 and (crystall\$7 or re adj crystall\$7)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:30
S24	467	S22 not S23	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/17 18:49
S25	101	((ion near2 implant\$5) or dop\$3) near (surface near (((single or mono) near2 crystall\$4) or semiconductor))near2 (layer\$1 or film\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/17 18:58
S26	267	((ion near2 implant\$5) or dop\$3) near (surface near (semiconductor near2 (layer\$1 or film\$1)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/17 19:00
S27	11	("5289030" "5468987" "5892244" "5897328" "5904550" "5915173" "5930608" "5949091" "5965904" "6011608" "6013928").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/03/17 19:03